



Technical Data Sheet

Opto Interrupter

ITR8307/S18

■ Features

- Fast response time
- High sensitivity
- Cut-Off visible wavelength
- Thin
- Compact
- Pb free
- This product itself will remain within RoHS compliant version.



■ Descriptions

ITR8307/F43 is a light reflection switch which includes a GaAs IR-LED transmitter and a NPN photo-transistor with a high sensitive receiver for short distance, operating in the infrared range. Both components are mounted side-by-side in a plastic package.

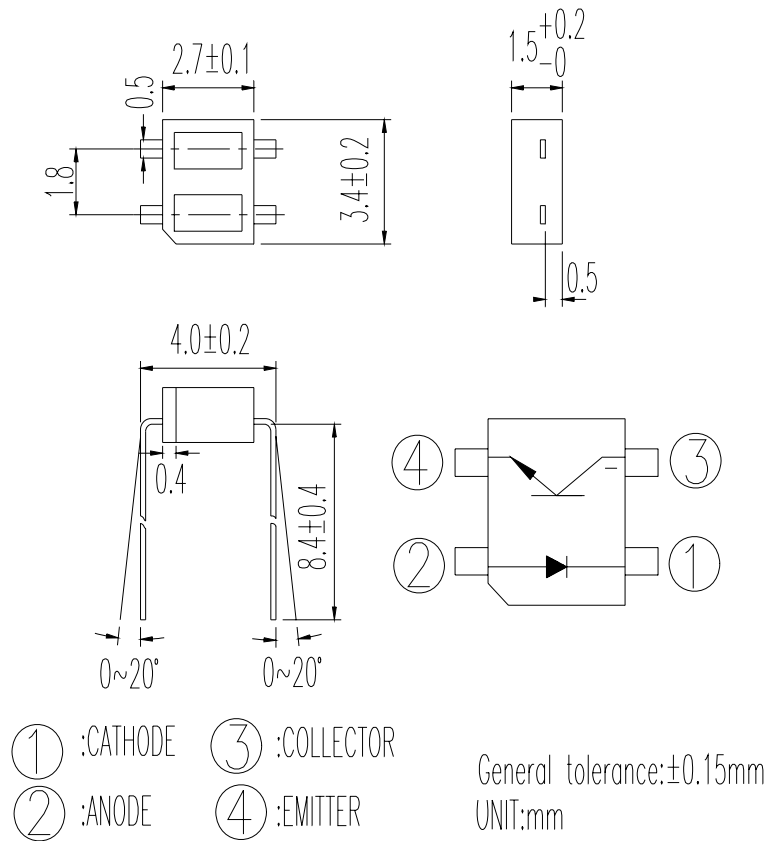
■ Applications

- Camera
- VCR
- Floppy disk driver
- Cassette type recorder
- Various microcomputer control equipment

■ Device Selection Guide

Device No.	Chip Material
IR	GaAs
PT	Silicon

Package Dimensions



Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1)	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	100	mW
	Collector Current	I _C	50	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		T _{opr}	-25~+85	°C
Storage Temperature		T _{stg}	-30~+90	°C
Lead Soldering Temperature (*2)		T _{sol}	260	°C

(* 1) tw=100 μ sec. , T=10 msec.

(* 2) t=5 Sec

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V_F	--	1.2	1.6	V	$I_F=20\text{mA}$
	Reverse Current	I_R	--	--	10	μA	$V_R=6\text{V}$
	Peak Wavelength	λ_P	--	940	--	nm	$I_F=20\text{mA}$
Output	Dark Current	I_{CEO}	--	--	1	μA	$V_{CE}=10\text{V}$, $I_F=0\text{mA}$
Transfer Characteristics	Collector Current	$I_{C(ON)}$	0.3	--	0.8	mA	$V_{CE}=5\text{V}$, $I_F=20\text{mA}$
	Leakage Current	I_{LEAK}	--	--	1	μA	$V_{CE}=2\text{V}$, $I_F=4\text{mA}$
	Rise time	t_r	--	20	--	μs	$V_{CE}=2\text{V}$ $I_C=10\text{mA}$
	Fall time	t_f	--	20	--	μs	$R_L=100\Omega$, $d=1\text{mm}$

Rank

 Conditions : $I_F=20\text{mA}$ $V_{CE}=5\text{V}$

 Unit: μA

Bin number	Min	Max
B	300	600
C	500	800

Typical Electrical/Optical/Characteristics Curves for IR

Fig. 1 Forward Current vs. Ambient Temperature

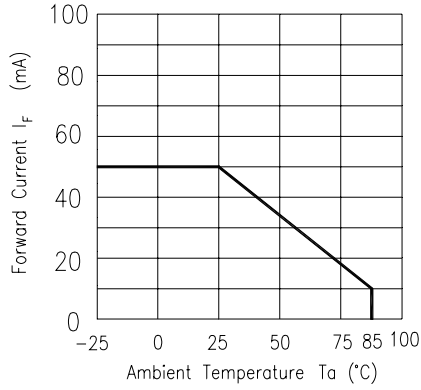


Fig. 2 Spectral Distribution

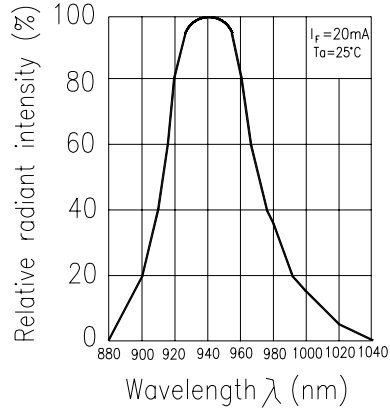


Fig. 3 Peak Emission Wavelength vs. Ambient Temperature

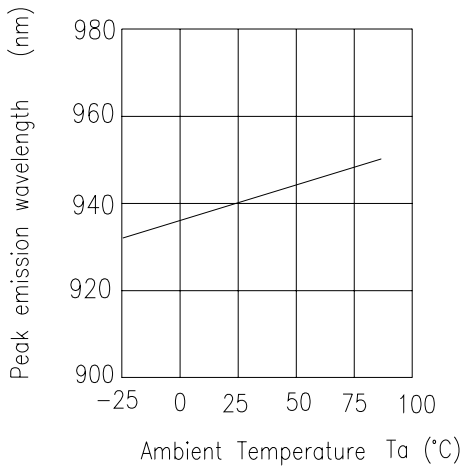


Fig. 4 Forward Current vs. Forward Voltage

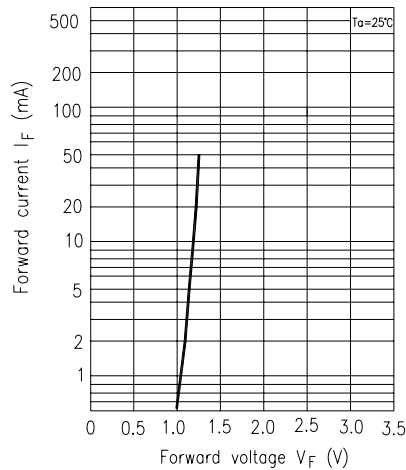


Fig. 5 Forward Voltage vs. Ambient Temperature

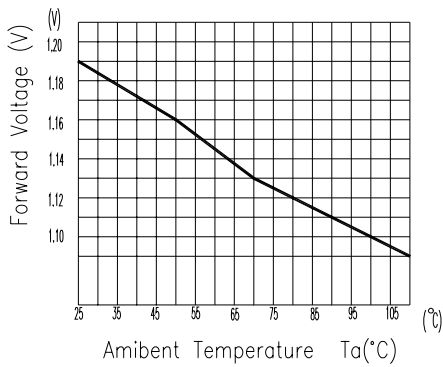
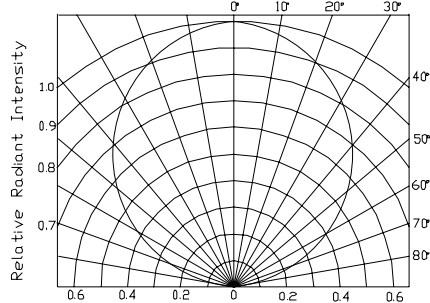


Fig. 6 Relative Radiant Intensity vs. Angular Displacement



Typical Electrical/Optical/Characteristics Curves for PT

Fig.1 Collector Power Dissipation vs. Ambient Temperature

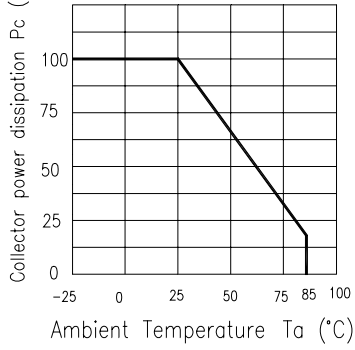


Fig.2 Collector Dark Current vs. Ambient Temperature

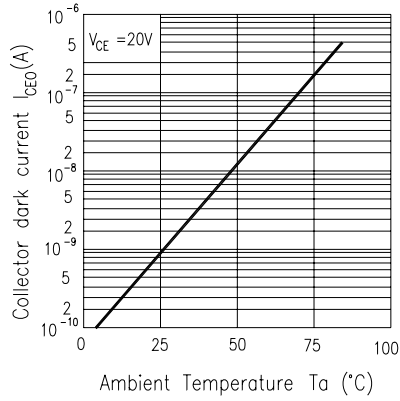


Fig. 3 Relative Collector Current vs. Ambient Temperature

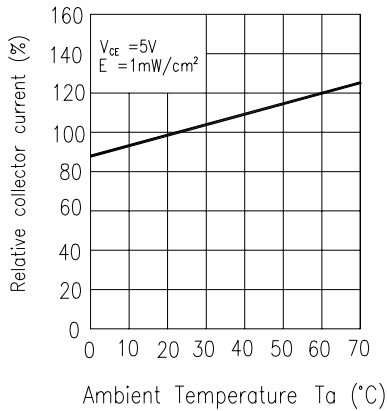


Fig.4 Collector Current vs. Irradiance

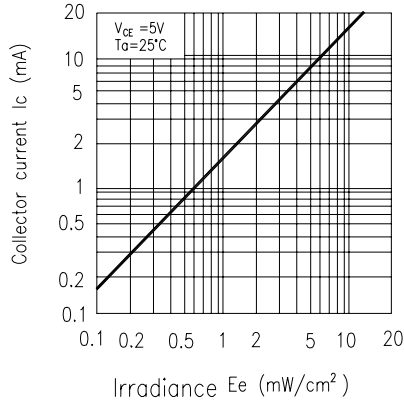


Fig.5 Spectral Sensitivity

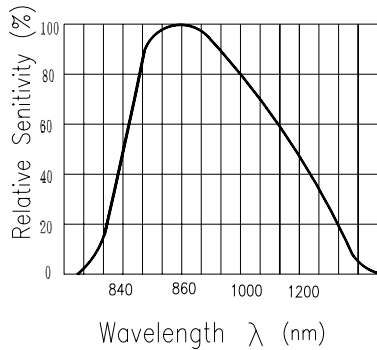
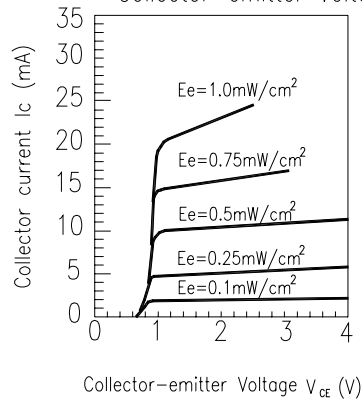


Fig.6 Collector Current vs. Collector-emitter Voltage



Typical Electrical/Optical/Characteristics Curves for ITR

Fig.1 Relative Collector Current vs. Distance between Sensor and Al Evaporation Galss

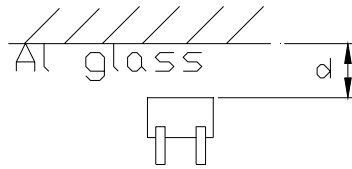
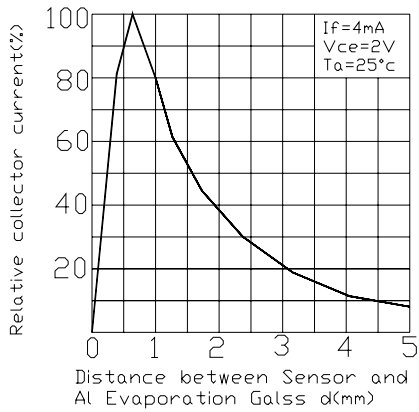


Fig.2 Relative Collector Current vs. Card Moving Distance (l)

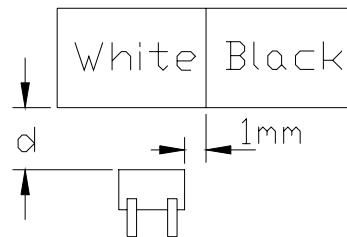
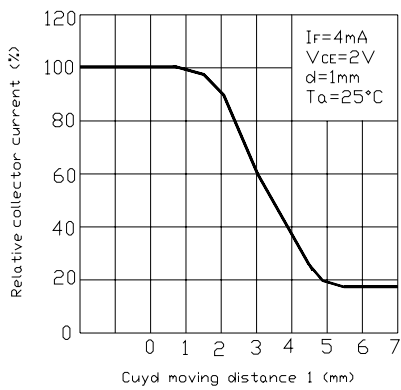
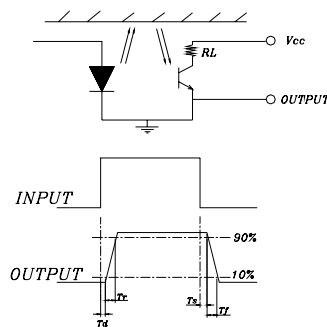
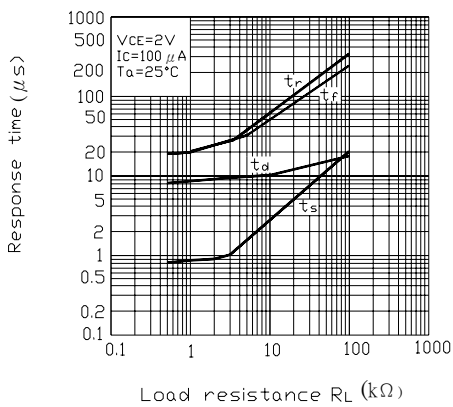


Fig.3 Response Time vs. Load Resistance



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

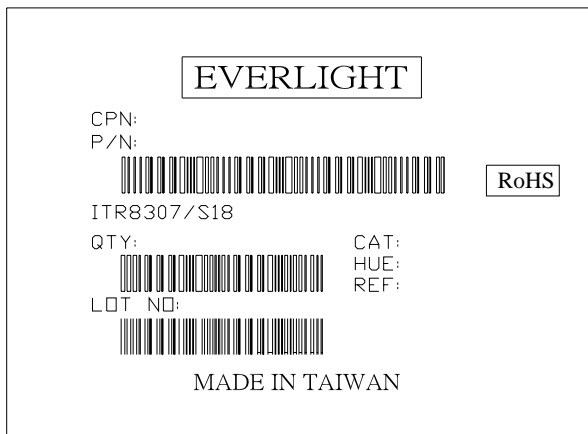
Confidence level : 90% LTPD : 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs	Ic(ON) ≤ Lx0.8 U : Upper Specification Limit L : Lower Specification Limit	0/1
2	Temperature Cycle	H : +85°C 30mins ↑ 5mins ↓ 30mins L : -30°C	50Cycles	22pcs		0/1
3	Thermal Shock	H : +85°C 5mins ↑ 10secs ↓ 5mins L : -10°C	50Cycles	22pcs		0/1
4	High Temperature Storage	TEMP. : +90°C	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP. : -30°C	1000hrs	22pcs		0/1
6	DC Operating Life	I _F =20mA	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1

Packing Quantity Specification

1. 160 Pcs/ Per Tube
2. 18 Tubes / Inner Carton
3. 12 Inner Cartons / Outside Carton

Label Form Specification



CPN: Customer's Production Number
P/N : Production Number
QTY: Packing Quantity
CAT: Ranks
HUE: Peak Wavelength
REF: Reference
LOT No: Lot Number
MADE IN TAIWAN: Production Place

Recommended Method of Storage

The following are general recommendations for moisture sensitive level (MSL) 4 storage and use :

- Shelf life in sealed bag: 12 months at < 40 °C and < 90% relative humidity (RH)
- After bag is opened, devices that will be subjected to reflow solder or other high temperature process must :
 - a) Mounted within 72 hours of factory conditions < 30 °C/60%RH, or
 - b) Stored at <20% RH
- Devices require bake, before mounting, if :
 - Humidity Indicator Card is > 20% when read at 23 ± 5 °C
- If baking is required, devices may be baked :
 - a) 192 hours at 40°C, and <5% RH(dry air/nitrogen) or
 - b) 96 hours at 60°C, and <5% RH for all device containers
 - c) 24 hours at 125 °C

Notes

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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